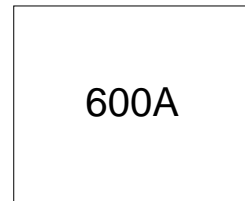


**Features**

- Wide current range
- High voltage ratings up to 3200V
- High surge current capabilities
- Stud cathode and stud anode version
- Standard JEDEC types

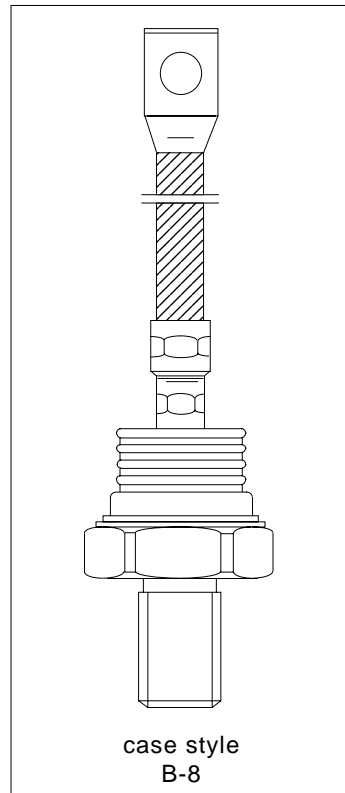


**Typical Applications**

- Converters
- Power supplies
- Machine tool controls
- High power drives
- Medium traction applications

**Major Ratings and Characteristics**

Parameters	SD600N/R		Units
	04 to 20	22 to 32	
$I_{F(AV)}$	600	600	A
@ $T_C$	92	54	°C
$I_{F(RMS)}$	940	940	A
$I_{FSM}$ @ 50Hz	13000	10500	A
@ 60Hz	13600	11000	A
$I^2t$ @ 50Hz	845	551	KA <sup>2</sup> s
@ 60Hz	772	503	KA <sup>2</sup> s
$V_{RRM}$ range	400 to 2000	2200 to 3200	V
$T_J$	- 40 to 180	- 40 to 150	°C



**ELECTRICAL SPECIFICATIONS**

Voltage Ratings

Type number	Voltage Code	$V_{RRM}$ , maximum repetitive peak reverse voltage V	$V_{RSM}$ , maximum non-repetitive peak rev. voltage V	$I_{RRM}$ max. @ $T_J = T_J$ max. mA
SD600N/R	04	400	500	35
	08	800	900	
	12	1200	1300	
	16	1600	1700	
	20	2000	2100	
	22	2200	2300	
	28	2800	2900	
	32	3200	3300	

Forward Conduction

Parameter	SD600N/R		Units	Conditions		
	04 to 20	22 to 32				
$I_{F(AV)}$ Max. average forward current @ Case temperature	600	600	A	180° conduction, half sine wave		
	92	54	°C			
$I_{F(AV)}$ Max. average forward current @ Case temperature	570	375	A	180° conduction, half sine wave		
	100	100	°C			
$I_{F(RMS)}$ Max. RMS forward current	940	940	A	DC @ $T_C = 75^\circ\text{C}$ (04 to 20), $T_C = 36^\circ\text{C}$ (25 to 32)		
$I_{FSM}$ Max. peak, one-cycle forward, non-repetitive surge current	13000	10500	A	t = 10ms	No voltage	Sinusoidal half wave, Initial $T_J = T_J$ max.
	13600	11000		t = 8.3ms	reapplied	
	10900	8830		t = 10ms	100% $V_{RRM}$	
	11450	9250		t = 8.3ms	reapplied	
$I^2t$ Maximum $I^2t$ for fusing	845	551	KA <sup>2</sup> s	t = 10ms	No voltage	
	772	503		t = 8.3ms	reapplied	
	598	390		t = 10ms	100% $V_{RRM}$	
	546	356		t = 8.3ms	reapplied	
$I^2\sqrt{t}$ Maximum $I^2\sqrt{t}$ for fusing	8450	5510	KA <sup>2</sup> √s	t = 0.1 to 10ms, no voltage reapplied		
$V_{F(TO)1}$ Low level value of threshold voltage	0.78	0.84	V	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$ , $T_J = T_J$ max.		
$V_{F(TO)2}$ High level value of threshold voltage	0.87	0.88		$(I > \pi \times I_{F(AV)})$ , $T_J = T_J$ max.		
$r_{f1}$ Low level value of forward slope resistance	0.35	0.40	mΩ	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$ , $T_J = T_J$ max.		
$r_{f2}$ High level value of forward slope resistance	0.31	0.38		$(I > \pi \times I_{F(AV)})$ , $T_J = T_J$ max.		
$V_{FM}$ Max. forward voltage drop	1.31	1.44	V	$I_{pk} = 1500\text{A}$ , $T_J = T_J$ max, $t_p = 10\text{ms}$ sinusoidal wave		

**Thermal and Mechanical Specifications**

Parameter	SD600N/R		Units	Conditions
	04 to 20	22 to 32		
T <sub>J</sub> Max. junction operating temperature range	-40 to 180	-40 to 150	°C	
T <sub>stg</sub> Max. storage temperature range	-55 to 200	-55 to 200		
R <sub>thJC</sub> Max. thermal resistance, junction to case	0.1		K/W	DC operation
R <sub>thCS</sub> Max. thermal resistance, case to heatsink	0.04			Mounting surface, smooth, flat and greased
T Max. allowed mounting torque ±10%	50		Nm	Not lubricated threads
wt Approximate weight	454		g	
Case style	B-8			See Outline Table

**ΔR<sub>thJC</sub> Conduction**

(The following table shows the increment of thermal resistance R<sub>thJC</sub> when devices operate at different conduction angles than DC)

Conduction angle	Sinusoidal conduction	Rectangular conduction	Units	Conditions
180°	0.012	0.008	K/W	T <sub>J</sub> = T <sub>J</sub> max.
120°	0.014	0.014		
90°	0.017	0.019		
60°	0.025	0.026		
30°	0.042	0.042		

**Ordering Information Table**

**Device Code**

<b>SD</b>	<b>60</b>	<b>0</b>	<b>N</b>	<b>32</b>	<b>P</b>	<b>C</b>
1	2	3	4	5	6	7

- 1** - Diode
- 2** - Essential part number
- 3** - 0 = Standard recovery
- 4** - N = Stud Normal Polarity (Cathode to Stud)  
R = Stud Reverse Polarity (Anode to Stud)
- 5** - Voltage code: Code x 100 = V<sub>RRM</sub> (See Voltage Ratings table)
- 6** - P = Stud base B-8 3/4" 16UNF-2A
- 7** - C = ceramic cap

NOTE: For Metric Device M24 x 1.5 Contact Factory

**Outlines Table**

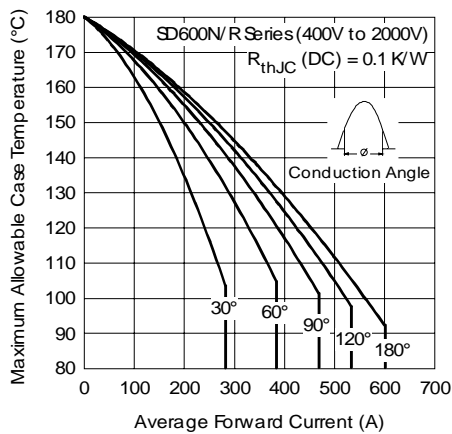
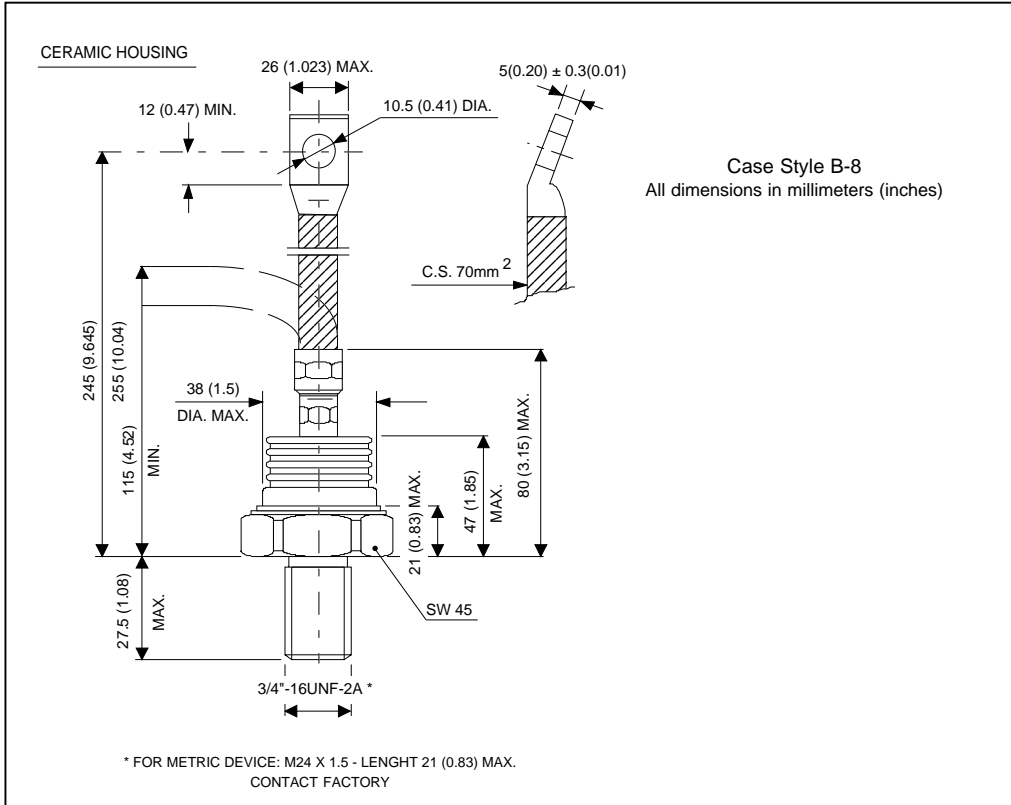


Fig. 1 - Current Ratings Characteristics

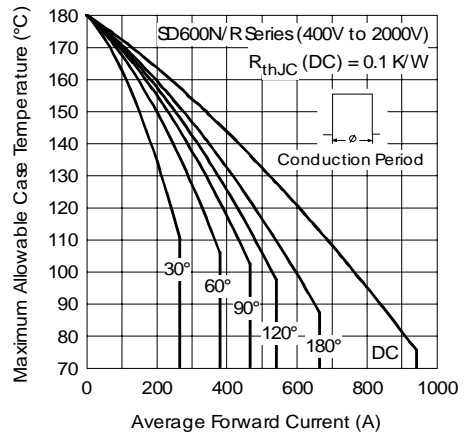


Fig. 2 - Current Ratings Characteristics

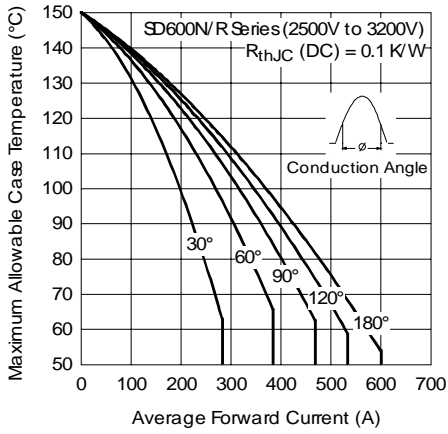


Fig. 3 - Current Ratings Characteristics

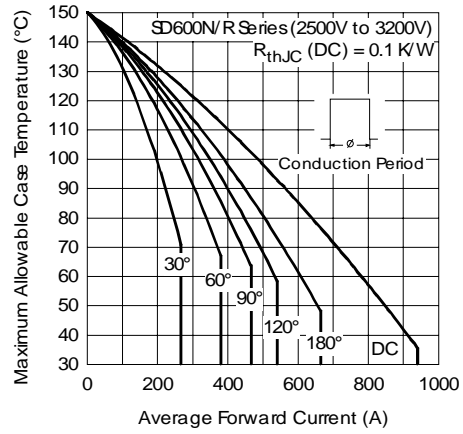


Fig. 4 - Current Ratings Characteristics

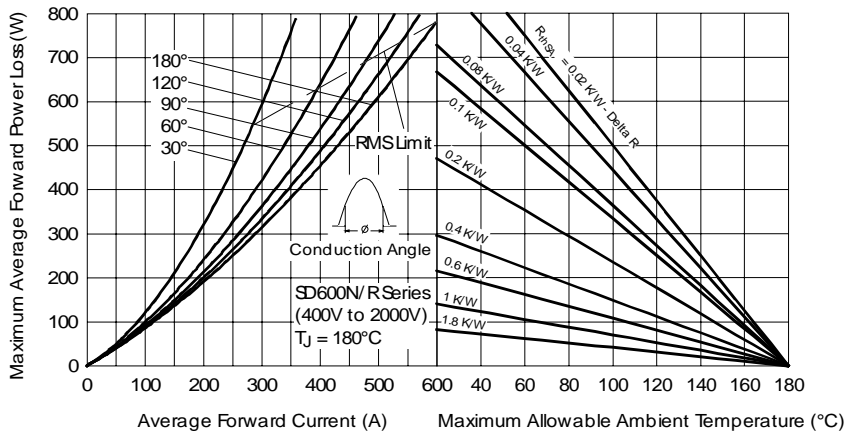


Fig. 5 - Forward Power Loss Characteristics

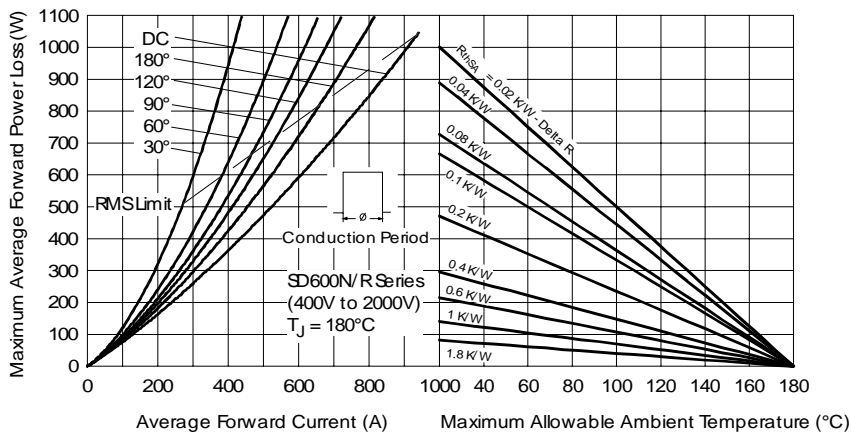


Fig. 6 - Forward Power Loss Characteristics

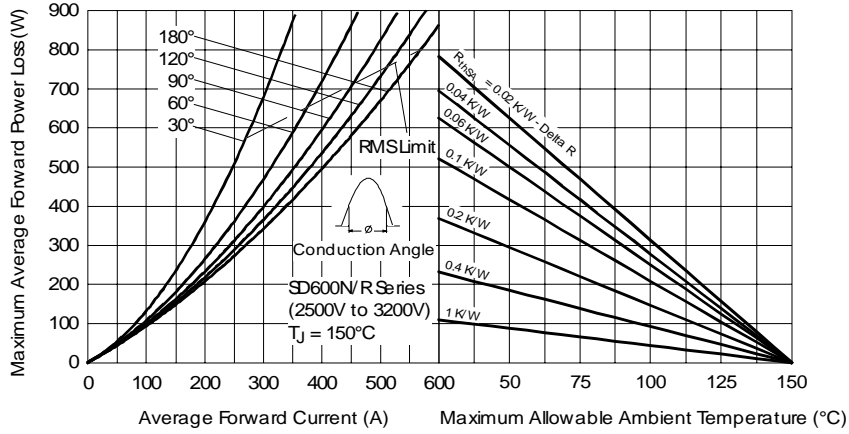


Fig. 7 - Forward Power Loss Characteristics

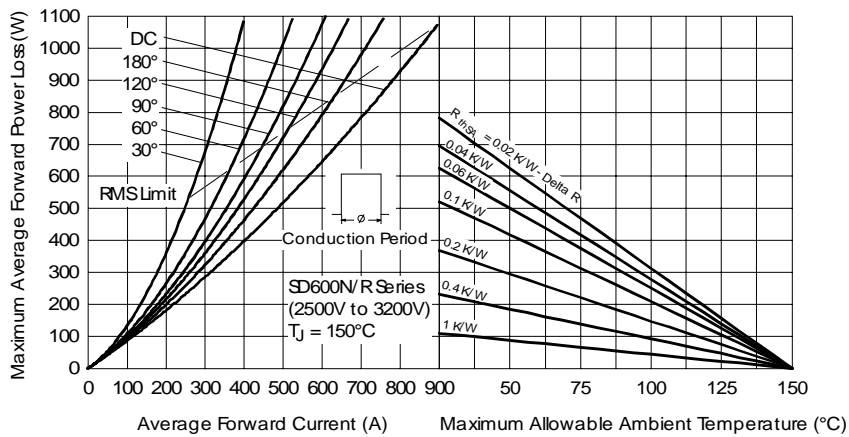


Fig. 8 - Forward Power Loss Characteristics

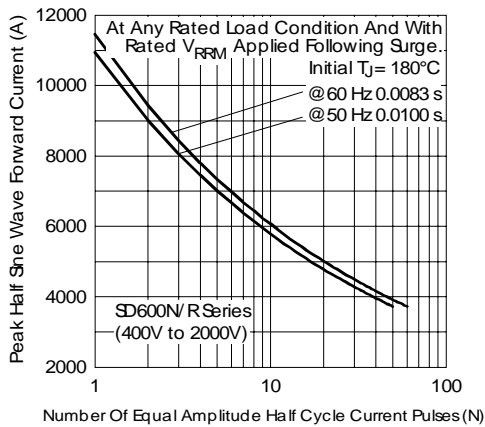


Fig. 9 - Maximum Non-Repetitive Surge Current

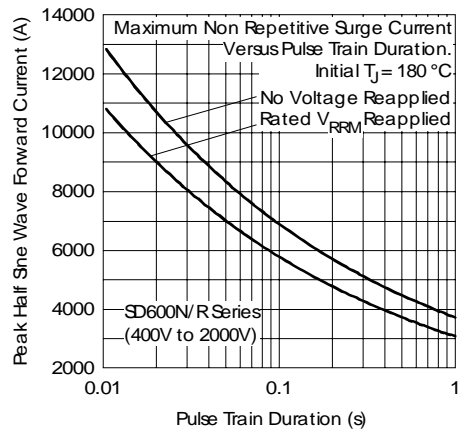


Fig. 10 - Maximum Non-Repetitive Surge Current

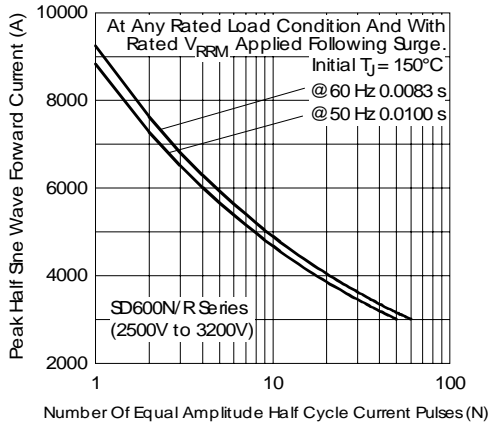


Fig. 11 - Maximum Non-Repetitive Surge Current

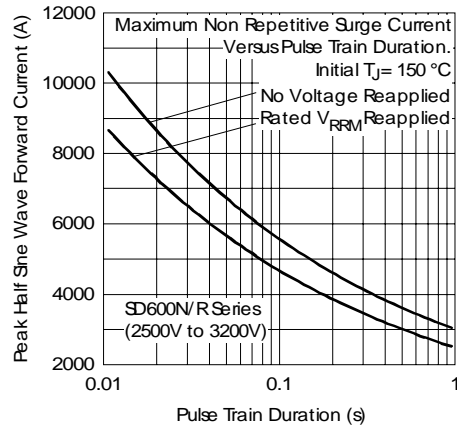


Fig. 12 - Maximum Non-Repetitive Surge Current

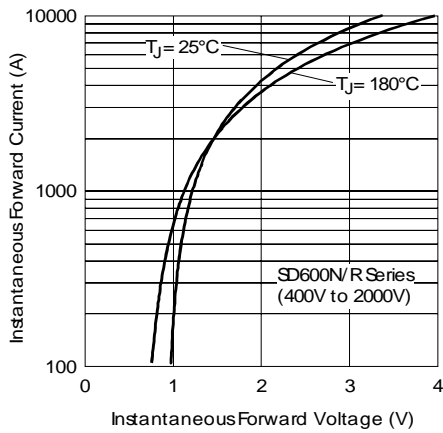


Fig. 13 - Forward Voltage Drop Characteristics

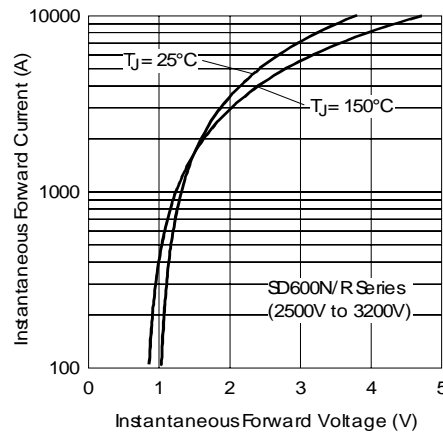


Fig. 14 - Forward Voltage Drop Characteristics

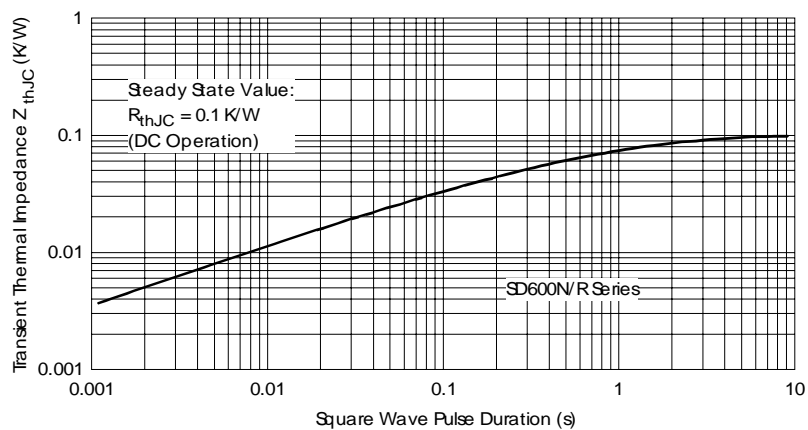


Fig. 15 - Thermal Impedance  $Z_{thJC}$  Characteristics

**SD600N/R Series**

Bulletin I2070 rev. C 03/03

International  
**IOR** Rectifier

---

Data and specifications subject to change without notice.  
This product has been designed and qualified for Industrial Level.  
Qualification Standards can be found on IR's Web site.

International  
**IOR** Rectifier

**IR WORLD HEADQUARTERS:** 233 Kansas St., El Segundo, California 90245, USA Tel: (310) 252-7105  
TAC Fax: (310) 252-7309  
Visit us at [www.irf.com](http://www.irf.com) for sales contact information. 03/03